



RN1106MFV,L3F Information

Heisener.com

Part Number RN1106MFV,L3F

Manufacturer Toshiba Semiconductor and Storage Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single, Pre-Biased

Description TRANS PREBIAS NPN

Package -

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









RN1106MFV,L3F Specifications

Manufacturer Part Number	RN1106MFV,L3F
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Package	-
Series	-
Transistor Type	NPN - Pre-Biased
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	4.7k
Resistor - Emitter Base (R2) (Ohms)	47k
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 10mA, 5V
Vce Saturation (Max) @ Ib, Ic	300mV @ 500μA, 5mA
Current - Collector Cutoff (Max)	500nA
Frequency - Transition	-
Power - Max	150mW
Mounting Type	-
Package / Case	-
Supplier Device Package	-
	Report errors?

RN1106MFV,L3F Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RN1106MFV,L3F Payment Methods



















RN1106MFV,L3F Shipping Methods













If you have any question about RN1106MFV,L3F, please do not hesitate to contact us!

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